NSN 5961-01-356-4297

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-4297 **Inclosure Material:** Ceramic **Overall Length:** Between 0.770 inches and 0.830 inches **Overall Height:** 0.105 inches **Overall Width:** Between 0.290 inches and 0.325 inches **Component Name And Quantity:** 12 semiconductor device diode **Mounting Method: Terminal Features Provided:** Electrostatic sensitive and burn in and hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 3.5 forward voltage, dc all semiconductor **Current Rating Per Characteristic:** 20.00 amperes forward current, average peak all semiconductor device diode **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 16 pin **Specification Data:** 90536-7908689 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No